

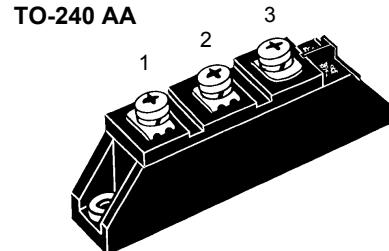
# Fast Recovery Epitaxial Diode (FRED) Module

**MEA 75-12 DA**  
**MEK 75-12 DA**  
**MEE 75-12 DA**

**V<sub>RRM</sub> = 1200 V**  
**I<sub>FAV</sub> = 75 A**  
**t<sub>rr</sub> = 250 ns**

## Preliminary data

V <sub>RSM</sub> V	V <sub>RRM</sub> V	Type	MEA75-12 DA	MEK 75-12 DA	MEE 75-12 DA
1200	1200		1 2 3	1 2 3	1 2 3

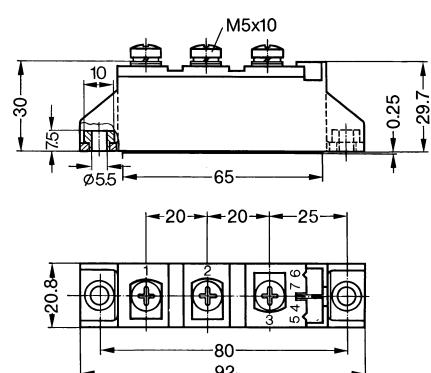


Symbol	Test Conditions	Maximum Ratings	
I <sub>FRMS</sub>	T <sub>case</sub> = 75 °C	107	A
I <sub>FAV</sub>	T <sub>case</sub> = 75 °C; rectangular, d = 0.5	75	A
I <sub>FRM</sub>	t <sub>p</sub> < 10 µs; rep. rating, pulse width limited by T <sub>VJM</sub>	TBD	A
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz), sine	1200	A
	t = 8.3 ms (60 Hz), sine	1300	A
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine	1080	A
	t = 8.3 ms (60 Hz), sine	1170	A
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C; t = 10 ms (50 Hz), sine	7200	A <sup>2</sup> s
	t = 8.3 ms (60 Hz), sine	7100	A <sup>2</sup> s
	T <sub>VJ</sub> = 150°C; t = 10 ms (50 Hz), sine	5800	A <sup>2</sup> s
	t = 8.3 ms (60 Hz), sine	5700	A <sup>2</sup> s
T <sub>VJ</sub>		-40...+150	°C
T <sub>stg</sub>		-40...+125	°C
T <sub>Hmax</sub>		110	°C
P <sub>tot</sub>	T <sub>case</sub> = 25°C	280	W
V <sub>ISOL</sub>	50/60 Hz, RMS t = 1 min	3000	V~
	I <sub>ISOL</sub> ≤ 1 mA t = 1 s	3600	V~
M <sub>d</sub>	Mounting torque (M5)	2.50-4/22-35	Nm/lb.in.
	Terminal connection torque (M5)	2.50-4/22-35	Nm/lb.in.
d <sub>S</sub>	Creep distance on surface	12.7	mm
d <sub>A</sub>	Strike distance through air	9.6	mm
a	Maximum allowable acceleration	50	m/s <sup>2</sup>
Weight		90	g

Symbol	Test Conditions	Characteristic Values (per diode) typ. max.	
I <sub>R</sub>	T <sub>VJ</sub> = 25°C V <sub>R</sub> = V <sub>RRM</sub>	2	mA
	T <sub>VJ</sub> = 25°C V <sub>R</sub> = 0.8 • V <sub>RRM</sub>	0.5	mA
	T <sub>VJ</sub> = 125°C V <sub>R</sub> = 0.8 • V <sub>RRM</sub>	34	mA
V <sub>F</sub>	I <sub>F</sub> = 100 A; T <sub>VJ</sub> = 125°C	1.85	V
	T <sub>VJ</sub> = 25°C	2.17	V
	I <sub>F</sub> = 300 A; T <sub>VJ</sub> = 125°C	2.58	V
	T <sub>VJ</sub> = 25°C	2.64	V
V <sub>T0</sub>	For power-loss calculations only	1.48	V
r <sub>T</sub>		3.65	mΩ
R <sub>thJH</sub>	DC current	0.550	K/W
R <sub>thJC</sub>	DC current	0.450	K/W
t <sub>rr</sub> I <sub>RM</sub>	I <sub>F</sub> = 150 A T <sub>VJ</sub> = 100°C 250	300	ns
	V <sub>R</sub> = 600 V T <sub>VJ</sub> = 25°C	22	A
	-di/dt = 200 A/µs T <sub>VJ</sub> = 100°C	33	A

Data according to IEC 60747  
 IXYS reserves the right to change limits, test conditions and dimensions

## Dimensions in mm (1 mm = 0.0394")



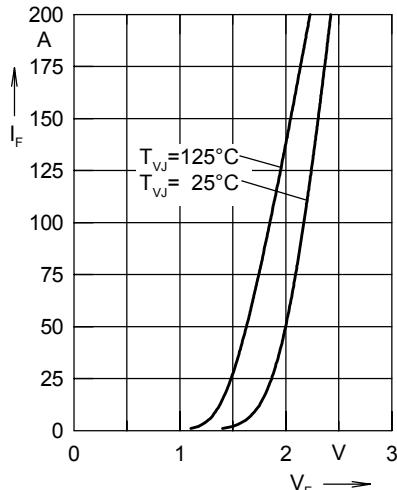


Fig. 1 Forward current  $I_F$  versus voltage drop  $V_F$  per leg

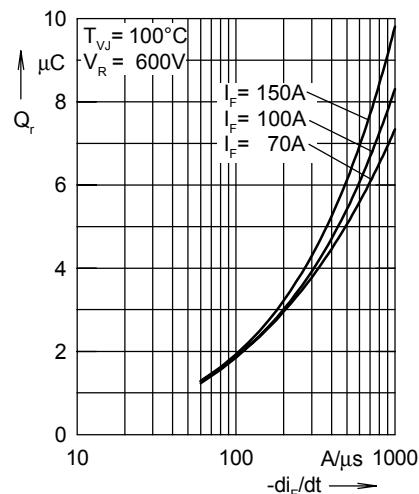


Fig. 2 Reverse recovery charge  $Q_r$  versus  $-di_F/dt$

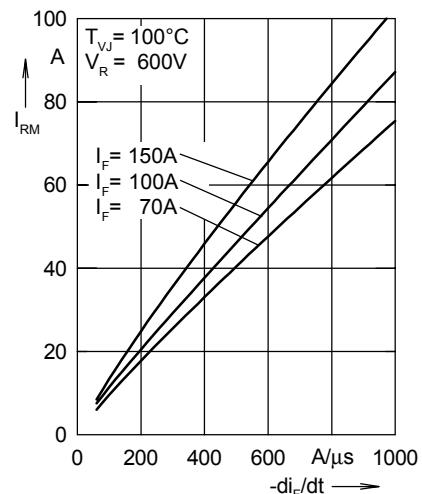


Fig. 3 Peak reverse current  $I_{RM}$  versus  $-di_F/dt$

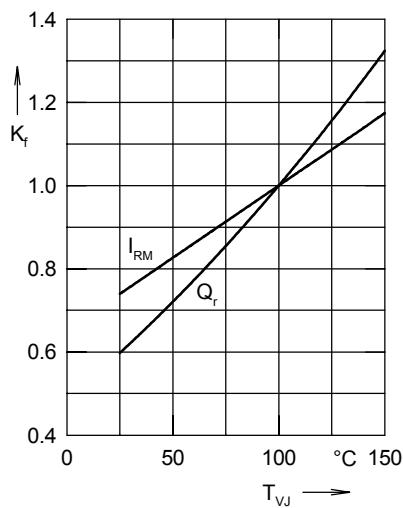


Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus junction temperature  $T_{VJ}$

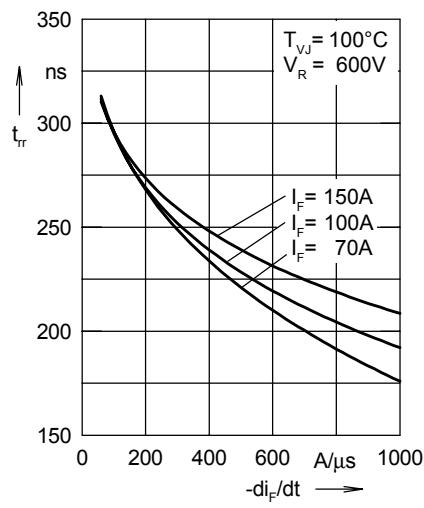


Fig. 5 Recovery time  $t_{rr}$  versus  $-di_F/dt$

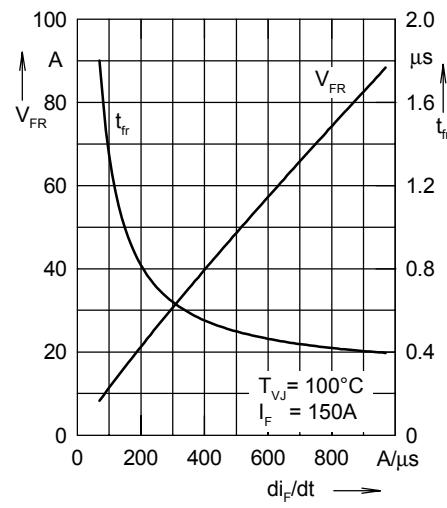


Fig. 6 Peak forward voltage  $V_{FR}$  and  $t_{rr}$  versus  $di_F/dt$

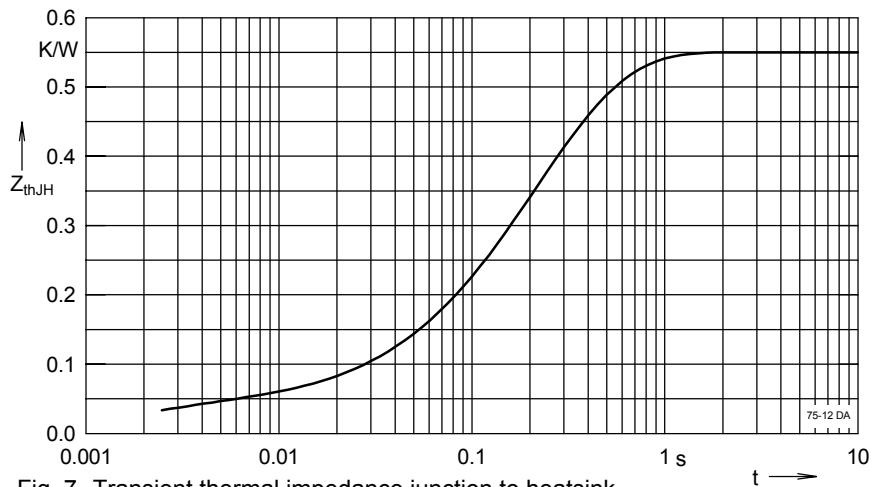


Fig. 7 Transient thermal impedance junction to heatsink

Constants for  $Z_{thJH}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.037	0.002
2	0.138	0.134
3	0.093	0.25
4	0.282	0.274